
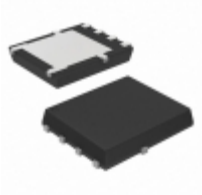
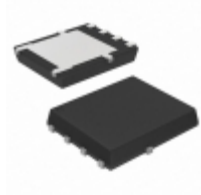
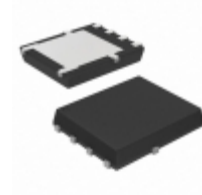
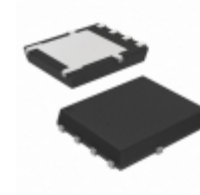
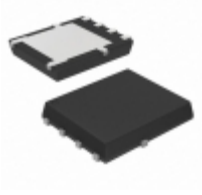
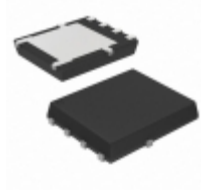
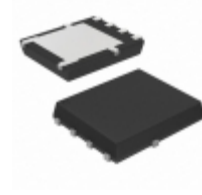
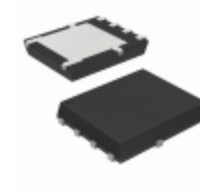
	<h2 style="color: #E67E22;">NVMFS5C430NT3G</h2>
	<p>Hersteller-Teilenummer: NVMFS5C430NT3G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 40V SO8FL</p> <hr/> <p>Datenblätter:  NVMFS5C430NT3G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NVMFS5C430NT3G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 40V SO8FL
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	Require For Quote & Check Stock
VGS (th) (Max) @ Id	3.5V @ 250µA
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Serie	-
Rds On (Max) @ Id, Vgs	1.7 mOhm @ 50A, 10V
Verlustleistung (max)	3.8W (Ta), 106W (Tc)
Verpackung	Tape & Reel (TR)
Verpackung / Gehäuse	8-PowerTDFN
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Eingabekapazität (Ciss) (Max) @ Vds	3300pF @ 25V
Gate Charge (Qg) (Max) @ Vgs	47nC @ 10V
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	-

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RFQ NVMFS5C430NT3G E-Mail: Info@Y-IC.com

Sie können auch interessiert

<p>sein:</p>  <p>NVMFS5C430NWFT3G ON Semiconductor MOSFET N-CH 40V SO8FL</p>	 <p>NVMFS5C430NLWFAFT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 38A 200A 5DFN</p>	 <p>NVMFS5C430NLWFAFT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 38A 200A 5DFN</p>	 <p>NVMFS5C430NWFT1G ON Semiconductor MOSFET N-CH 40V SO8FL</p>
 <p>NVMFS5C430NT1G ON Semiconductor MOSFET N-CH 40V SO8FL</p>	 <p>NVMFS5C430NLWFT1G ON Semiconductor MOSFET N-CH 40V 200A SO8FL</p>	 <p>NVMFS5C430NWFAFT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 35A 185A 5DFN</p>	 <p>NVMFS5C430NLWFT3G ON Semiconductor MOSFET N-CH 40V 200A SO8FL</p>

Verwandtes Hot-Keyword

Mehr

NVMFS5C430NT3G AMI Semiconductor / ON Semiconductor	NVMFS5C430NT3G Datenblatt	NVMFS5C430NT3G-Datenblätter	NVMFS5C430NT3G PDF	AMI Semiconductor / ON Semiconductor NVMFS5C430NT3G
NVMFS5C430NT3G Electronic	NVMFS5C430NT3G-Komponenten	NVMFS5C430NT3G-Verteiler	NVMFS5C430NT3G-Bild	NVMFS5C430NT3G-Teil
NVMFS5C430NT3G Preis	NVMFS5C430NT3G Hersteller	NVMFS5C430NT3G Bild	NVMFS5C430NT3G Aktie	NVMFS5C430NT3G Inventar
NVMFS5C430NT3G Neu	NVMFS5C430NT3G Original	NVMFS5C430NT3G garantiert	NVMFS5C430NT3G RFQ	NVMFS5C430NT3G Online bestellen

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